Surface States and the Photoelectron-Spin Polarization of Ni(100)

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High-resolution angle-resolved photoelectron emission spectra for Ni(100) are reported which identify a magnetic surface state just below the Fermi level. This surface state exists throughout the surface Brillouin zone including the zone-center $\Gamma$ where its room-temperature binding energy and intrinsic width are 0.11 and 0.15 eV, respectively. These new results provide additional insight into the long-standing electron-spin polarization-sign-reversal controversy.

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Spin-polarized photoelectron emission studies of single-crystal Ni surfaces reported by Eib and Alvarado\textsuperscript{1} have stimulated considerable interest recently. The most striking experimental feature for the (100) Ni surface is the abrupt sign reversal of measured electron-spin polarization (ESP) at approximately 0.1 eV above emission threshold. This result has direct bearing on several important issues related to the inability of one-electron band theory to account for the valence spectra of Ni. Several explanations for the abrupt sign change have been proposed based on distinctively different mechanisms, and at present, the issues are not completely resolved.

Smith and Chiang\textsuperscript{2} have considered the polarization sign reversal within the framework of a three-step model and conclude that a surface-derived photoemission process is needed to explain the observed behavior near threshold. Two distinct surface processes have been proposed. One model, proposed by Moore and Pendry,\textsuperscript{3} involves a rigorous photoemission calculation which includes photoemission via evanescent low-energy electron-diffraction (LEED) states resulting from the surface potential. This calculation utilizes a bulk band model for Ni having a Stoner gap of about 0.1 eV at the $X$ point as deduced from photoemissions data by Himpsel, Knapp, and Eastman.\textsuperscript{4} A second model, proposed by Dempsey and Kleinman,\textsuperscript{5} is based on emission from a majority-spin surface state which is found just below the Fermi energy in parametrized calculations of the energy bands for a 35-layer (100) Ni crystal.

Moore and Pendry's explanation requires an $X_5$ exchange splitting of approximately 0.33 eV, a value considerably smaller than 0.88 eV obtained by Wang and Callaway\textsuperscript{4} based on one-electron band theory. As discussed by Liebsch,\textsuperscript{7} the reduced exchange splitting along with the experimentally observed band narrowing, the large quasiparticle damping and shakeup satellites associated with Ni band spectra can all be understood semiquantitatively based on correlation effects involving 3$d$ electrons. Kleinman\textsuperscript{8} has also shown that correlation effects can reduce the $X_5$ exchange splitting and account for band narrowing, but maintains that a majority-spin surface state accounts for the ESP sign reversal.

Plummer and Eberhardt\textsuperscript{9} have used angle-resolved photoelectron emission to probe for surface states on the (100) surface of nickel. They found a narrow surface sensitive peak near the Fermi energy which could be clearly identified as a surface state in regions of the surface Brillouin zone approaching the zone edge in both the [10] and [11] directions. The peaks became increasingly difficult to characterize as surface states near the center of the two-dimensional zone because of competing emission features. By projecting the bulk bands onto the surface Brillouin zone, they demonstrated that the observed states are magnetic, but it was not possible to relate these surface states directly to the ESP sign reversal because near emission threshold, the most important region of the surface Brillouin zone is centered around $\Gamma$, the zone center.

This paper reports results of experiments based on suggestions by Plummer and Eberhardt\textsuperscript{9} which more clearly indicate the extent that surface states are related to the ESP sign reversal: very high-resolution measurements to determine the actual binding energy and intrinsic width of the surface states, and temperature-dependent studies to probe for exchange effects associated with the surface states. In conducting these experiments, it was possible to show that a feature characteristic of surface states exists at $\Gamma$ in the surface Brillouin zone. This new result supports the theoretical predictions of Dempsey and Kleinman\textsuperscript{5} and provides an alternate explanation for the long-standing sign reversal controversy based
on direct experimental results.

The experiments reported here were conducted using a high-intensity resonance lamp based on a design reported by Shevchik and a Physical Electronics twin-pass cylindrical-mirror analyzer (CMA) equipped with an angle-resolving drum and a coaxial electron gun for Auger analysis. The sample geometry, shown in Fig. 1, permits sweeping crystal-momentum space along a symmetry direction by either rotating the crystal in the plane of light incidence (angle $\alpha$) or by rotating both the crystal and the CMA drum (angles $\alpha$ and $\phi$). In the experiments reported here, a 4° angle resolving aperture (angle $\Omega$) was used and the angles of incidence $\theta = (\alpha - \gamma)$ correspond to predominantly $s$-polarized light.

The nickel crystal was spark cut and aligned to approximately $\pm 1^\circ$ with use of x-ray Laue techniques, and the orientation of the crystal in the sample mount was checked with use of the same method. Standard cleaning techniques involving argon-ion sputtering, annealing in oxygen, and flushing to high temperatures were used to clean the crystal. Auger analysis was used to ensure that the surface was clean or had only the desired adsorbate impurities. Sulphur and oxygen were adsorbed on the surface (by admitting H$_2$S or O$_2$) to test the sensitivity of the surface-state features to chemisorbed layers.

Figure 2 shows high-resolution photoelectron spectra for the (100) crystal face of nickel for values of $k_\parallel$ around $\bar{1}$. Here $k_\parallel$ is given by

$$k_\parallel = \left[ \frac{2m}{\hbar^2} E_{\text{kin}} \right]^{1/2} \sin \theta_\parallel,$$

where $E_{\text{kin}}$ is the electron kinetic energy and $\theta_\parallel$ is the emission angle.

FIG. 1. Experimental geometry: points $A$, $B$, $L$, $N$, and $F$ are in the same plane; $AA$, CMA axis; $F$, target point; $LF$, axis of incident photons; $NF$ axis of sample normal; emission angle $\theta_\parallel = \pi/2 - \theta - \alpha$.

FIG. 2. Angle-resolved photoelectron spectra near the $\bar{1}$ point of a nickel (100) surface. The $k_\parallel$ values correspond to the $\bar{1}-\bar{M}$ direction. Resolution: 70 meV x 3%. Selected energy distribution curves were taken at 40-meV resolution. Incident light is predominately $s$ polarized.

measured from the normal. A common feature of these spectra is a narrow peak (or shoulder in some cases) near the Fermi level. This feature satisfies the conditions for a surface state: (i) The binding energy at fixed $k_\parallel$ exhibits no dispersion as the perpendicular component of $k$ is changed, (ii) analogous spectra (same $k_\parallel$ and $\hbar \omega$) after exposure to O$_2$ and H$_2$S show that the peak near $E_F$ has higher sensitivity to chemisorption than other features of the spectra, (iii) the binding energy of the peak puts it in an absolute gap of the majority-spin bulk band structure as shown in Fig. 6 of Ref. 9.

Allowed bulk transitions are $\Delta_{\pm} \rightarrow \Delta_{\pm}$, and $\Delta_{\pm} \rightarrow \Delta_{\pm}$. The predicted surface state couples to $s$-polarized light, and $\Delta_{\pm}$ transitions are forbidden for $s$ polarization. The experimental data exhibit increased emission strength of the feature attributed to a surface state as $s$ polarization is increased. The opposite would be expected if the peak were due to $\Delta_{\pm}$ transitions. Also, both $\Delta_{\pm}$ and $\Delta_0$ bulk transitions should yield observable dispersion at fixed $k_{\parallel}$. The only reasonable conclusion is the peak near $E_F$ is due to a magnetic surface state.

The binding energy and intrinsic width of the peak near $E_F$ were determined by measuring energy distribution curves at successively higher
analyzer resolution (by decreasing the pass energy of the analyzer). The actual resolution was judged from the sharpness of the Fermi edge, but a "theoretical" resolution of approximately 40 meV was achieved with use of the 10.20-, 16.85-, and 21.22-eV lines, and 100 meV with use of the 40.61-eV line. To obtain the actual width and binding energy near $\Gamma$, the 21.22-eV spectra at $k_y = 0$ and $k_y = 0.35 \text{ Å}^{-1}$ were analyzed with use of a curve-fitting routine which optimized the fit of a double Gaussian function

$$Y(E) = C_1 \exp\left[-(E - \mu_1)^2/2\sigma_1^2\right] + C_2 \exp\left[-(E - \mu_2)^2/2\sigma_2^2\right]$$

to the experimental data. No background contribution is included in the fit, and no correction for the Fermi function was used in fitting the room-temperature data. This was justified based on nearly identical experimental results obtained at 60°K (see Fig. 3). Note also that the shoulder in the 21-eV $k_y = 0$ spectra is outside the selected energy range used in modeling. Neglecting this structure introduces negligible error in placing the center and width of the peak near $E_F$.

The parameters given in Table I establish the binding energy $\mu_2$ and intrinsic width full width at half maximum (FWHM) $= 2\sigma_2 (2 \ln 2)^{1/2}$ of the structure at $\bar{\Gamma}$: $\mu_2 = -0.11 \text{ eV}$ and FWHM $= 0.146 \text{ eV}$. These parameters are compatible with the trend apparent in Fig. 7 of Plummer and Eberhardt's paper which illustrates intrinsic width versus binding energy for other surface states identified on metal surfaces. The experimental data (Fig. 2) suggest that the structure disperses downward from $E_F$ away from $\bar{\Gamma}$, and at $k_y = 1.02 \text{ Å}^{-1}$ has a binding energy of 0.14 eV.

The temperature dependence of the structure near $E_F$ was studied in order to observe the influence of exchange effects. During these experiments, the temperature was measured by a Chromel-Alumel thermocouple spotwelded to the back of the sample. Heating pulses were applied at 60 Hz at a duty cycle of less than 1/2. During the heating part of a cycle, the counting electronics were gated off to avoid measuring any influence of the magnetic field on electron trajectories. The sample could also be cooled to below 60°K.

Figure 3 illustrates the temperature dependence near $\bar{\Gamma}$. Data obtained at 60°K matched room-temperature results as stated before. At higher temperatures clear evidence of temperature broadening of the Fermi level appears in the experimental data. Computer modeling with use of the double Gaussian function indicates that the emission from the peak at $E_F$ is reduced relative to the peak at 0.6 eV. Taking into account the Fermi function, it was determined that this decrease in amplitude is accompanied by a small shift of the peak toward the Fermi energy. Auger

![Graph showing temperature dependence of photoelectron spectra](image)

**FIG. 3.** Temperature dependence of the photoelectron spectra at $h\nu = 0.35 \text{ Å}^{-1}$ taken at 21.2-eV photon energy. Resolution: 40 meV × 2%. Data taken at low temperature (60°K) was nearly identical to the 30°C spectra. Shaded region of lower curve illustrates typical effect of sulfur or oxygen chemisorption (~1 D). (1 langmuir = 1 L = 1 μTorr sec.)

<table>
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<th>$C_2$</th>
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<th>$\mu_2$ (eV)</th>
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**TABLE I.** Parameters for the double Gaussian function (see text) which yield a best fit to room-temperature experimental data at $h\nu = 21.2$ eV.
Observation of the Meissner Effect in an Organic Superconductor


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A partial Meissner effect, fully diamagnetic shielding signals, and large anisotropies in the upper and lower critical fields in ditetramethyltetraselenafulvalene-hexafluorophosphate [(TMTSF)$_2$PF$_6$] under applied hydrostatic pressure are observed.

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The compound ditetramethyltetraselenafulvalene-hexafluorophosphate [(TMTSF)$_2$PF$_6$] is a highly conducting linear-chain organic crystal. At atmospheric pressure, Bechgaard et al. have observed a conductivity $\sigma \approx 10^5$ (\Omega cm)$^{-1}$ near a temperature of 20 K. Below about 15 K the material enters a semiconducting state which resembles the Peierls state observed in a number of similar compounds. At a hydrostatic pressure $P = 1.2$ GPa, Jerome et al. have found that the semiconducting transition is absent and that there is a new transition at 0.9 K where $\sigma$ increases by over 10$^5$. With the application of magnetic fields of order 200 Oe, the transition temperature $T_c$ drops, and the magnitude of the rise in $\sigma$ decreases to ~5. Subsequent ac susceptibility measurements at a frequency $\nu = 68$ Hz show an anomaly indicative of a transition into a diamagnetic state. Jerome et al. have suggested that [(TMTSF)$_2$PF$_6$] at $P = 1.2$ GPa is a BCS superconductor.

Although there have been several theoretical models for high conductivity in one-dimensional